TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT process)

# 2SC4738FV

#### Audio Frequency General Purpose Amplifier Applications

Unit: mm

High Voltage: V<sub>CEO</sub> = 50 V
 High Current: I<sub>C</sub> = 150 mA (max)

• High h<sub>FE</sub>: h<sub>FE</sub> = 120 ~ 400

Excellent hFE Linearity

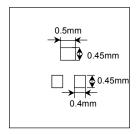
:  $h_{FE} (I_C = 0.1 \text{ mA})/h_{FE} (I_C = 2 \text{ mA}) = 0.95 (typ.)$ 

• Complementary to 2SA1832FV

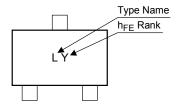
## Maximum Ratings (Ta = 25°C)

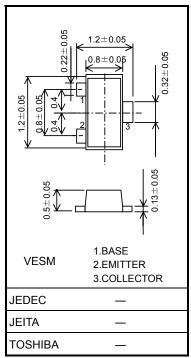
Characteristics	Symbol	Rating	Unit
Collector-base voltage	$V_{CBO}$	60	V
Collector-emitter voltage	V <sub>CEO</sub>	50	V
Emitter-base voltage	V <sub>EBO</sub>	5	V
Collector current	I <sub>C</sub>	150	mA
Base current	Ι <sub>Β</sub>	30	mA
Collector power dissipation	PC	150	mW
Junction temperature	Tj	150	°C
Storage temperature range	T <sub>stg</sub>	−55 <b>~</b> 150	°C

<sup>\*:</sup> Mounted on FR4 board (25.4 mm × 25.4 mm × 1.6mmt)



## Marking





Weight: 0.0015g (typ.)

# Electrical Characteristics (Ta = 25°C)

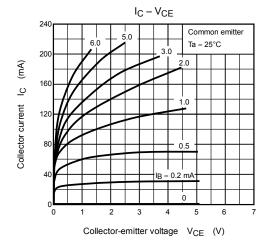
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I <sub>CBO</sub>	$V_{CB} = 60 \text{ V}, I_E = 0$	_	_	0.1	μΑ
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> = 5 V, I <sub>C</sub> = 0	_	_	0.1	μΑ
DC current gain	h <sub>FE</sub> (Note)	V <sub>CE</sub> = 6 V, I <sub>C</sub> = 2 mA	120	_	400	
Collector-emitter saturation voltage	V <sub>CE (sat)</sub>	$I_C = 100 \text{ mA}, I_B = 10 \text{ mA}$	_	0.1	0.25	٧
Transition frequency	f <sub>T</sub>	V <sub>CE</sub> = 10 V, I <sub>C</sub> = 1 mA	80	_	_	MHz
Collector output capacitance	C <sub>ob</sub>	$V_{CB} = 10 \text{ V}, I_{E} = 0, f = 1 \text{ MHz}$	_	2.0	_	pF

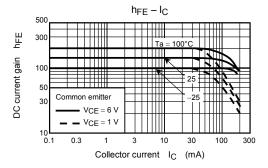
Note: hFE Classification

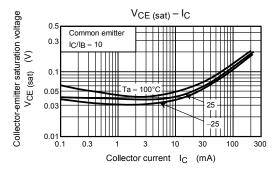
Y (Y): 120 ~ 240, GR (G): 200 ~ 400

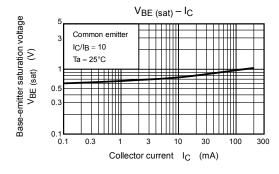
( ) Marking symbol

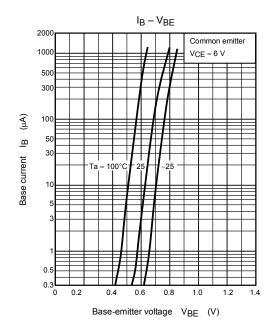
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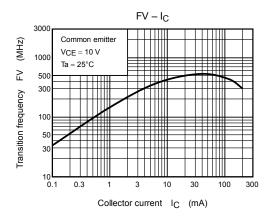


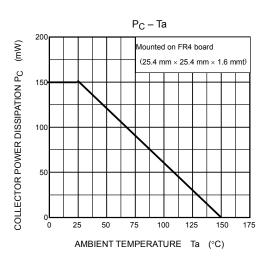












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